



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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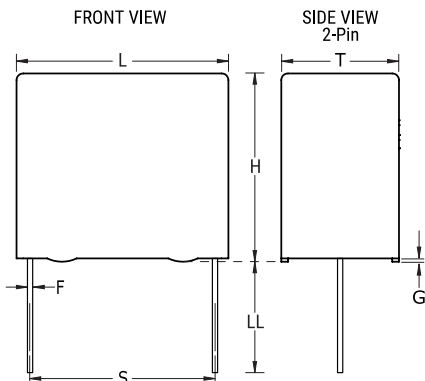
Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



KEMET Part Number: PHE448SB3470JR06
(F448BD471J2K0C)

PHE448/F448, Film, Film/Foil Polypropylene, General Purpose, 470 pF, 5%, 2000 VDC, 85C, Lead Spacing = 15mm



Dimensions	
L	18mm MAX
H	10.5mm MAX
T	5.5mm MAX
S	15mm +/-0.4mm
LL	6mm -1mm
F	0.8mm +/-0.05mm
G	0.5mm NOM

Packaging Specifications	
Packaging:	Bulk, Bag
Packaging Quantity:	1000

General Information	
Supplier:	KEMET
Series:	PHE448/F448
Dielectric:	Film/Foil Polypropylene
Style:	Radial
Features:	Pulse
RoHS:	Yes
Lead:	Wire Leads
AEC-Q200:	No
Miscellaneous:	Rthha= 86 C/W (85C), 0.2 m/s
Notes:	Not For New Design, Please Check Possible Alternative Parts (AltPart)

Specifications	
Capacitance:	470 pF
Capacitance Tolerance:	5%
Voltage AC:	700 VAC
Voltage DC:	2000 VDC, 1480 VDC (105C)
Temperature Range:	-55/+105C
Rated Temperature:	85C
Dissipation Factor:	0.03% 1kHz, 0.05% 10kHz, 0.1% 100kHz
Insulation Resistance:	63.8298 GOhms
Max dV/dt:	25000 V/us
Inductance:	6 nH